



2SB1118/2SD1618

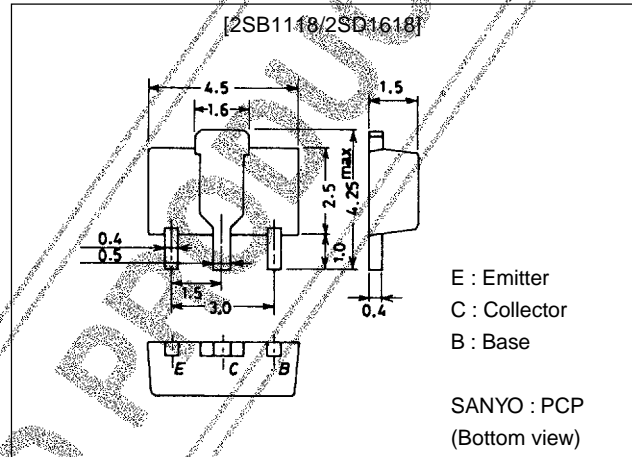
Low-Voltage High-Current Amplifier, Muting Applications

Features

- Low collector-to-emitter saturation voltage.
- Very small size making it easy to provide high-density, small-sized hybrid IC's.

Package Dimensions

unit:mm
2038



() : 2SB1118

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)20	V
Collector-to-Emitter Voltage	V _{CE0}		(-)15	V
Emitter-to-Base Voltage	V _{EB0}		(-)5	V
Collector Current	I _C		(-)0.7	A
Collector Current (Pulse)	I _{CP}		(-)1.5	A
Collector Dissipation	P _C	Mounted on ceramic board (250mm ² ×0.8mm)	500	mW
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =(-)15V, I _E =0			(-)0.1	μA
Emitter Cutoff Current	I _{EB0}	V _{EB} =(-)4V, I _C =0			(-)0.1	μA
DC Current Gain	h _{FE1}	V _{CE} =(-)2V, I _C =(-)50mA	140*		560*	
	h _{FE2}	V _{CE} =(-)2V, I _C =(-)500mA	60			
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)50mA		250		MHz

* ; The 2SB1118/2SD1618 are classified by 50mA h_{FE} as follows :

Marking 2SB1118 : BA
2SD1618 : DA
h_{FE} rank : S, T, U

140	S	280	280	T	400	280	U	560
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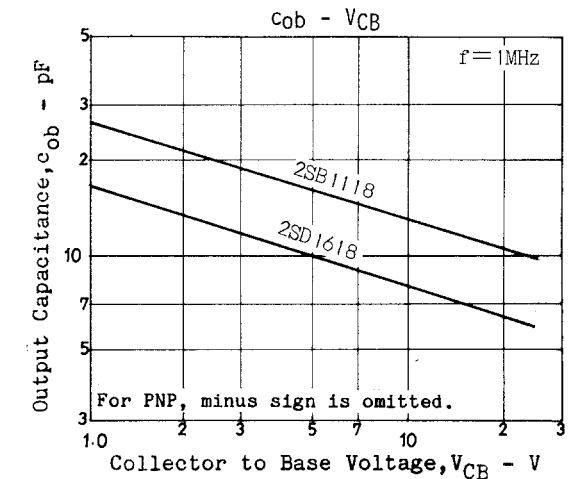
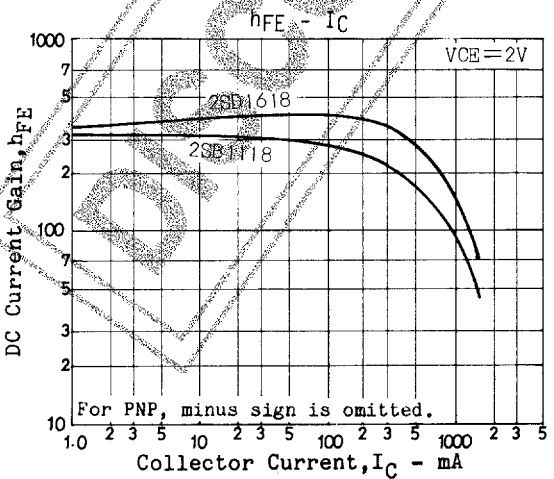
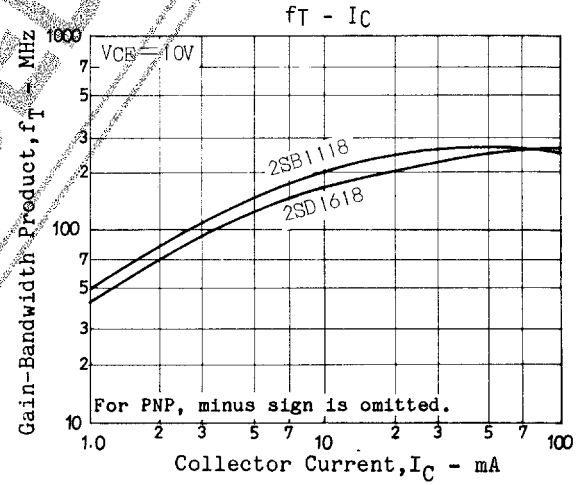
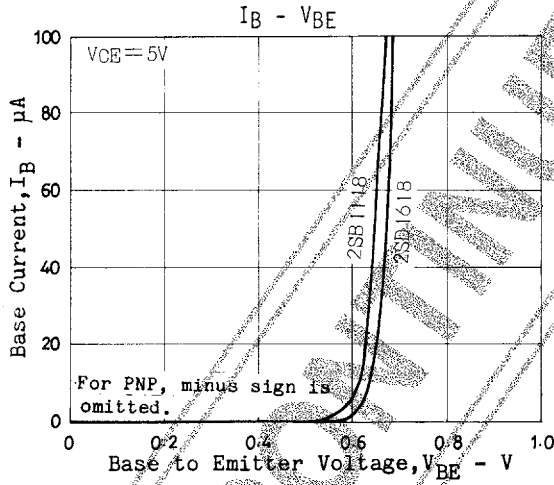
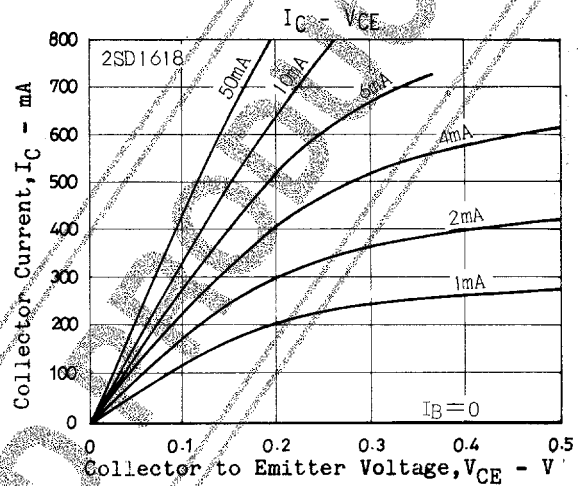
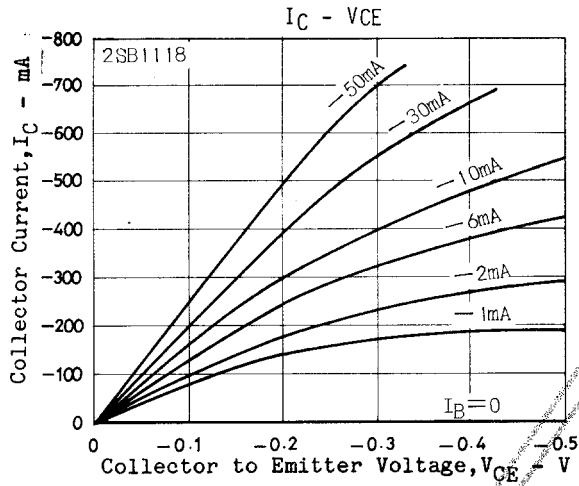
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SANYO Electric Co., Ltd. Semiconductor Business Headquarters

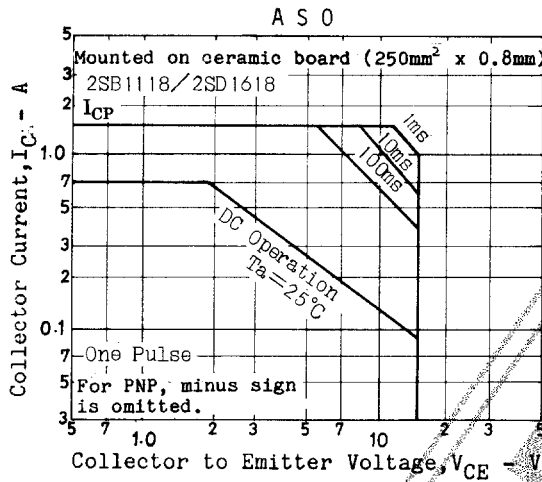
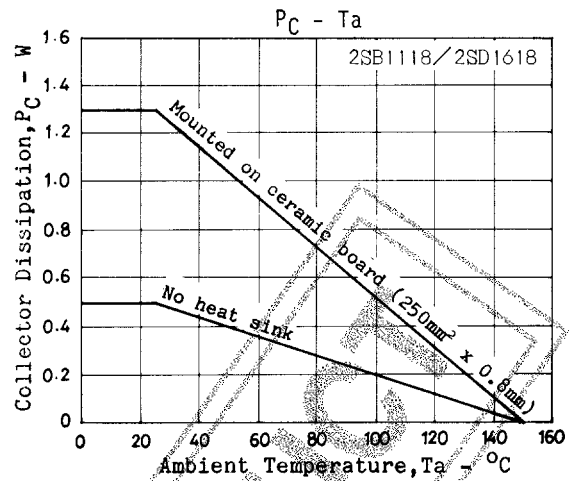
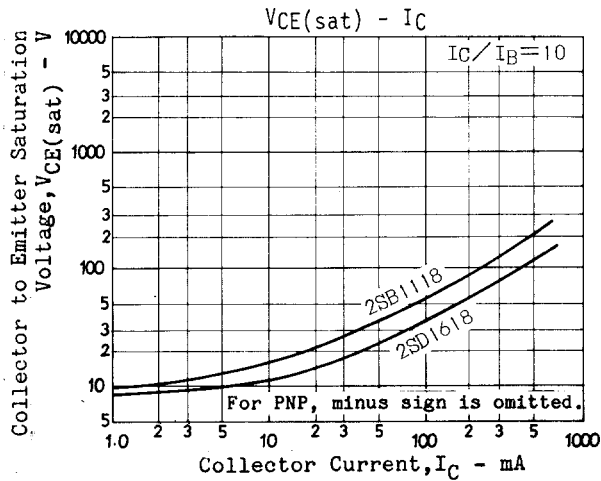
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=(-)5mA, I_B=(-)0.5mA$		10	25	mV
	$V_{CE(sat)2}$	$I_C=(-)100mA, I_B=(-)10mA$		(-15)	(-35)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)100mA, I_B=(-)10mA$		30	80	mV
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$		(-60)	(-120)	mV
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$		(-15)		V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$		(-5)		V
Output Capacitance	C_{ob}	$V_{CB}(-)10V, f=1MHz$		8		pF
				(13)		pF



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